



0.8 Ω , Low-Voltage, 4-Channel Analog Multiplexer

MAX4734

General Description

The MAX4734 is a low on-resistance, low-voltage, 4-channel CMOS analog multiplexer that operates from a single 1.6V to 3.6V supply. This device has fast switching speeds ($t_{ON} = 25\text{ns}$, $t_{OFF} = 20\text{ns}$ max), handles Rail-to-Rail® analog signals, and consumes less than 4 μW of quiescent power. The MAX4734 has break-before-make switching.

When powered from a 3V supply, the MAX4734 features low 0.8 Ω (max) on-resistance (R_{ON}), with 0.2 Ω (max) R_{ON} matching and 0.1 Ω R_{ON} flatness. The digital logic input is 1.8V CMOS compatible when using a single 3V supply.

The MAX4734 is available in space-saving 12-pin QFN (3mm x 3mm) and 10-pin μMAX packages.

Applications

Power Routing
Battery-Powered Systems
Audio and Video Signal Routing
Low-Voltage Data-Acquisition Systems
Communications Circuits
PCMCIA Cards
Cellular Phones
Modems
Hard Drives

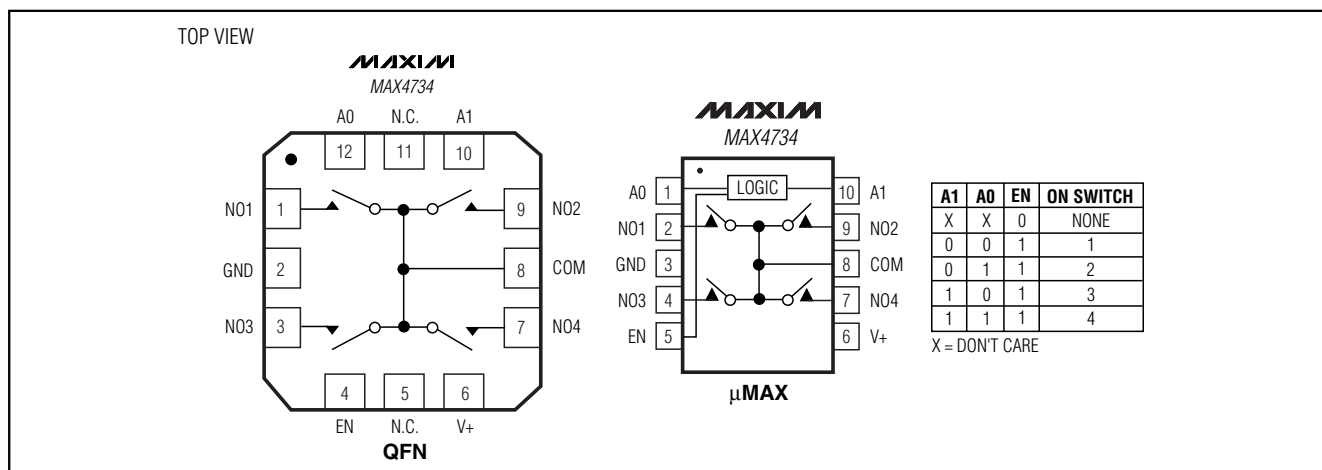
Features

- ◆ Low R_{ON}
0.8 Ω (max) (3V Supply)
2 Ω (max) (1.8V Supply)
- ◆ 0.1 Ω (max) R_{ON} Flatness (3V Supply)
- ◆ 1.6V to 3.6V Single-Supply Operation
- ◆ Available in QFN (3mm x 3mm) Package
- ◆ High-Current Handling Capacity (150mA Continuous)
- ◆ 1.8V CMOS-Logic Compatible (3V Supply)
- ◆ Fast Switching: $t_{ON} = 25\text{ns}$, $t_{OFF} = 20\text{ns}$

Ordering Information

PART	TEMP RANGE	PIN-PACKAGE
MAX4734EUB	-40°C to +85°C	10 μMAX
MAX4734EGC	-40°C to +85°C	12 QFN (3mm x 3mm)

Pin Configurations/Functional Diagrams/Truth Table



Rail-to-Rail is a registered trademark of Nippon Motorola, Ltd.



Maxim Integrated Products 1

For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

0.8 Ω , Low-Voltage, 4-Channel Analog Multiplexer

ABSOLUTE MAXIMUM RATINGS

Voltages Referenced to GND

V+, A ₋ , EN ₋	-0.3V to +4V
COM, NO ₋ (Note 1)	-0.3V to (V+ + 0.3V)
Continuous Current COM, NO ₋	±150mA
Continuous Current (all other pins)	±20mA
Peak Current COM, NO ₋ (pulsed at 1ms 10% duty cycle)	±300mA

Continuous Power Dissipation (T_A = +70°C)

10-Pin μ MAX (derate 5.6mW/°C above +70°C)	444mW
12-Pin QFN (derate 14.7mW/°C above +70°C)	1176mW
Operating Temperature Range	-40°C to +85°C
Maximum Junction Temperature	+150°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

Note 1: Signals on COM or NO₋ exceeding V+ or GND are clamped by internal diodes. Limit forward current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Single 3V Supply

(V+ = 2.7V to 3.6V, V_{IH} = 1.4V, V_{IL} = 0.5V, T_A = T_{MIN} to T_{MAX}, unless otherwise specified. Typical values are at V+ = 3.0V, T_A = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	T _A	MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Analog Signal Range	V _{COM} , V _{NO₋}			0		V+	V
On-Resistance (Note 4)	R _{ON}	V+ = 2.7V, I _{COM} = 100mA, V _{NO₋} = 1.5V	+25°C		0.6	0.8	Ω
			T _{MIN} to T _{MAX}			1	
On-Resistance Match Between Channels (Notes 4, 5)	ΔR_{ON}	V+ = 2.7V, I _{COM} = 100mA, V _{NO₋} = 1.5V	+25°C		0.1	0.2	Ω
			T _{MIN} to T _{MAX}			0.3	
On-Resistance Flatness (Note 6)	R _{FLAT(ON)}	V+ = 2.7V, I _{COM₋} = 100mA, V _{NO₋} = 1V, 1.5V, 2V	+25°C		0.05	0.1	Ω
			T _{MIN} to T _{MAX}			0.2	
NO ₋ Off-Leakage Current (Note 7)	I _{NO₋(OFF)}	V+ = 3.6V, V _{COM} = 0.3V, 3.3V, V _{NO₋} = 3.3V, 0.3V	+25°C	-1	±0.002	+1	nA
			T _{MIN} to T _{MAX}	-5		+5	
COM Off-Leakage Current (Note 7)	I _{COM(OFF)}	V+ = 3.6V, V _{COM} = 0.3V, 3.3V, V _{NO₋} = 3.3V, 0.3V	+25°C	-1	±0.002	+1	nA
			T _{MIN} to T _{MAX}	-5		+5	
COM On-Leakage Current (Note 7)	I _{COM(ON)}	V+ = 3.6V, V _{COM} = 3.3V, 0.3V, V _{NO₋} = 3.3V, 0.3V, or floating	+25°C	-2	±0.002	+2	nA
			T _{MIN} to T _{MAX}	-10		+10	

0.8Ω, Low-Voltage, 4-Channel Analog Multiplexer

MAX4734

ELECTRICAL CHARACTERISTICS—Single 3V Supply (continued)

(V₊ = 2.7V to 3.6V, V_{IH} = 1.4V, V_{IL} = 0.5V, T_A = T_{MIN} to T_{MAX}, unless otherwise specified. Typical values are at V₊ = 3.0V, T_A = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	T _A	MIN	TYP	MAX	UNITS
SWITCH DYNAMIC CHARACTERISTICS							
Turn-On Time	t _{ON}	V _{NO_} = 1.5V, R _L = 50Ω, C _L = 35pF, Figure 1	+25°C	20	25	ns	
			T _{MIN} to T _{MAX}	30			
Turn-Off Time	t _{OFF}	V _{NO_} = 1.5V, R _L = 50Ω, C _L = 35pF, Figure 1	+25°C	15	20	ns	
			T _{MIN} to T _{MAX}	25			
Break-Before-Make (Note 8)	t _{BBM}	V _{NO_} = 1.5V, R _L = 50Ω, C _L = 35pF, Figure 2	+25°C	5		ns	
			T _{MIN} to T _{MAX}	1			
Charge Injection	Q	V _{GEN} = 0, R _{GEN} = 0, C _L = 1.0nF, Figure 3	+25°C	60		pC	
NO_ Off-Capacitance	C _{OFF}	f = 1MHz, Figure 4	+25°C	33		pF	
COM Off-Capacitance	C _{COM(OFF)}	f = 1MHz, Figure 4	+25°C	117		pF	
COM On-Capacitance	C _{COM(ON)}	f = 1MHz, Figure 4	+25°C	171		pF	
-3dB On-Channel Bandwidth	BW	Signal = 0, R _{IN} = R _{OUT} = 50Ω, C _L = 5pF, Figure 5		90		MHz	
Off-Isolation (Note 9)	V _{ISO}	f = 1MHz, V _{COM} = 1V _{P-P} , R _L = 50Ω, C _L = 5pF, Figure 5	+25°C	-56		dB	
Crosstalk (Note 10)	V _{CT}	f = 1MHz, V _{COM} = 1V _{P-P} , R _L = 50Ω, C _L = 5pF, Figure 5	+25°C	-56		dB	
Total Harmonic Distortion	THD	f = 20Hz to 20kHz, V _{COM} = 2V _{P-P} , R _L = 32Ω	+25°C	0.018		%	
LOGIC INPUT (A_, EN)							
Input Logic High	V _{IH}			1.4		V	
Input Logic Low	V _{IL}			0.5		V	
Input Leakage Current	I _{IN}	V _{EN} = 0 or 3.6V, V _{A_} = 0 or 3.6V		-1	0.005	+1	μA
POWER SUPPLY							
Power-Supply Range	V+			1.6	3.6	V	
Positive Supply Current	I+	V+ = 3.6V, V _{EN} , A_ = 0 or V+, all channels on or off		0.004	1	μA	

0.8 Ω , Low-Voltage, 4-Channel Analog Multiplexer

ELECTRICAL CHARACTERISTICS—Single 1.8V Supply

($V_+ = 1.8V$, $V_{IH} = 1.0V$, $V_{IL} = 0.4V$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise specified. Typical values are at $T_A = +25^\circ C$.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	T _A	MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Analog Signal Range	V _{COM} , V _{NO_}			0		V+	V
On-Resistance	R _{ON}	I _{COM_} = 10mA, V _{NO_} = 1V	+25°C	1.5	2	Ω	
			T _{MIN} to T _{MAX}		3		
SWITCH DYNAMIC CHARACTERISTICS							
Turn-On Time	t _{ON}	V _{NO_} = 1V, R _L = 50Ω, C _L = 35pF, Figure 1	+25°C	25	30	ns	
			T _{MIN} to T _{MAX}		35		
Turn-Off Time	t _{OFF}	V _{NO_} = 1V, R _L = 50Ω, C _L = 35pF, Figure 1	+25°C	18	25	ns	
			T _{MIN} to T _{MAX}		28		
Break-Before-Make (Note 8)	t _{BBM}	V _{NO_} = 1V, R _L = 50Ω, C _L = 35pF, Figure 2	+25°C	7		ns	
			T _{MIN} to T _{MAX}	1			
Charge Injection	Q	V _{GEN} = 0, R _{GEN} = 0, C _L = 1nF, Figure 3	+25°C	35		pC	
Off-Isolation (Note 9)	V _{ISO}	f = 1MHz, V _{NO_} = 1V _{P-P} , R _L = 50Ω, C _L = 5pF, Figure 5	+25°C	-56		dB	
Crosstalk (Note 10)	V _{CT}	f = 1MHz, V _{COM} = 1V _{P-P} , R _L = 50Ω, C _L = 5pF, Figure 5	+25°C	-56		dB	
LOGIC INPUT (A ₋ , EN)							
Input Logic High	V _{IH}			1		V	
Input Logic Low	V _{IL}				0.4	V	
Input Leakage Current	I _{IN}	V _{EN} = 0 or 3.6V, V _{A_-} = 0 or 3.6V			1	μA	

Note 2: The algebraic convention, where the most negative value is a minimum and the most positive value is a maximum, is used in this data sheet.

Note 3: $-40^\circ C$ specifications are guaranteed by design.

Note 4: R_{ON} and ΔR_{ON} matching specifications for QFN packaged parts are guaranteed by design.

Note 5: $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$.

Note 6: Flatness is defined as the difference between the maximum and the minimum value of on-resistance as measured over the specified analog signal ranges.

Note 7: Leakage parameters are 100% tested at hot temperature and guaranteed by correlation at room temperature.

Note 8: Guaranteed by design.

Note 9: Off-Isolation = $20\log_{10}(V_{COM}/V_{NO-})$, V_{COM} = output, V_{NO-} = input to off switch.

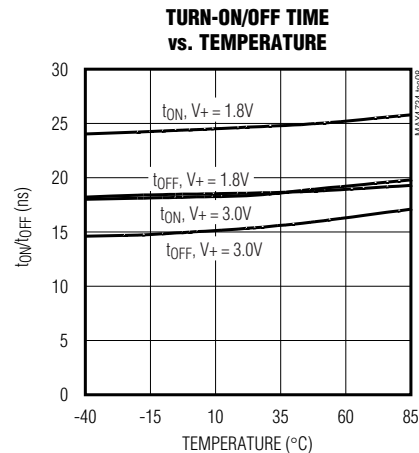
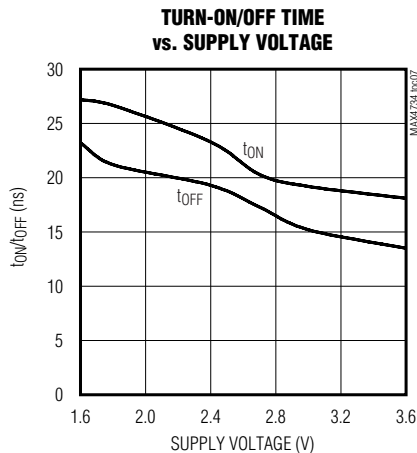
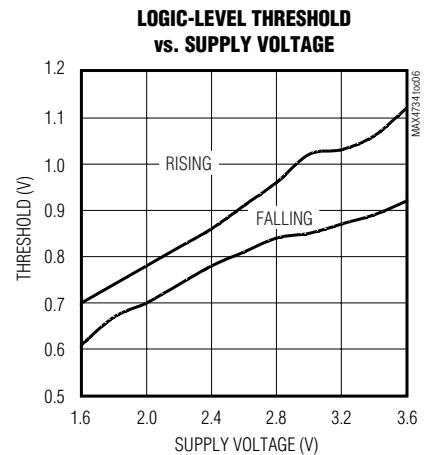
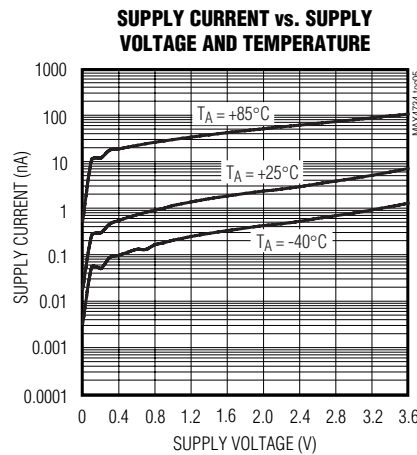
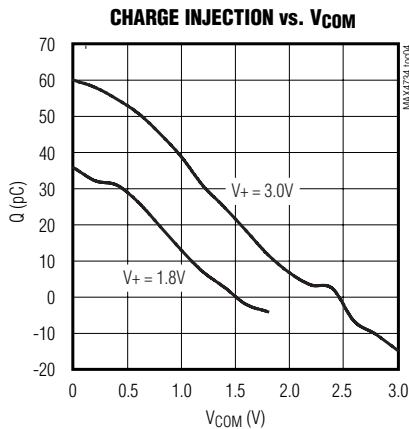
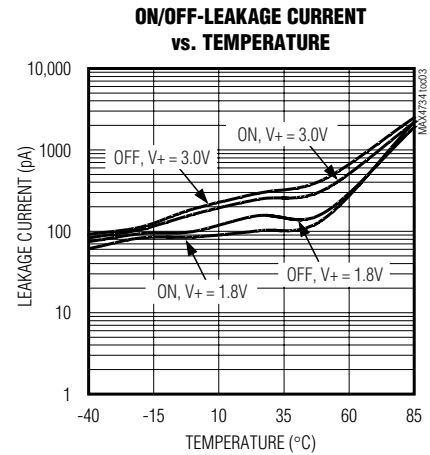
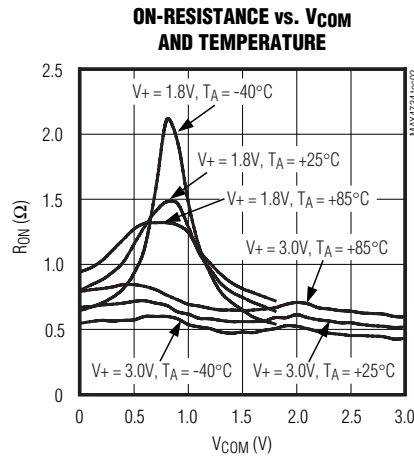
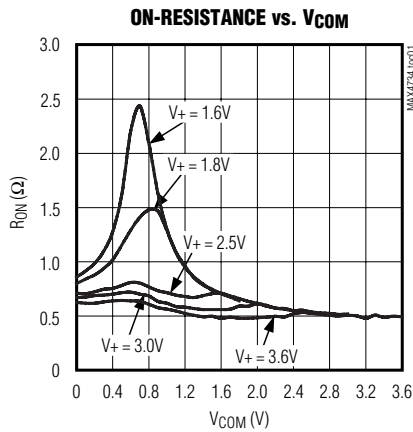
Note 10: Between two switches.

0.8 Ω , Low-Voltage, 4-Channel Analog Multiplexer

Typical Operating Characteristics

($T_A = +25^\circ\text{C}$, unless otherwise noted.)

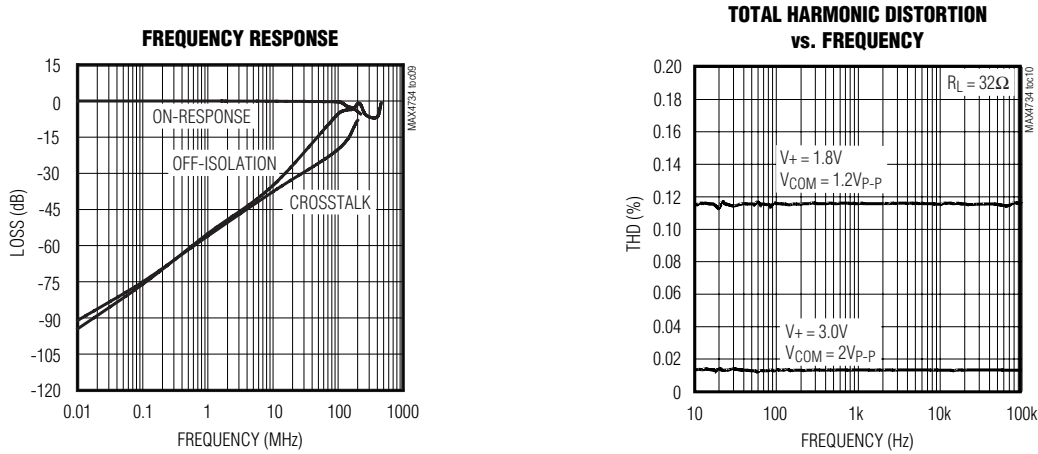
MAX4734



0.8Ω, Low-Voltage, 4-Channel Analog Multiplexer

Typical Operating Characteristics (continued)

(T_A = +25°C, unless otherwise noted.)



Pin Description

PIN		NAME	FUNCTION
μMAX	QFN		
1	12	A0	Address 0 Input
2	1	NO1	Analog Switch 1—Normally Open Terminal
3	2	GND	Ground
4	3	NO3	Analog Switch 3—Normally Open Terminal
5	4	EN	Enable Logic Input
6	6	V+	Positive-Supply Voltage Input
7	7	NO4	Analog Switch 4—Normally Open Terminal
8	8	COM	Analog Switch Common Terminal
9	9	NO2	Analog Switch 2—Normally Open Terminal
10	10	A1	Address 1 Input
—	5, 11	N.C.	No Connection

0.8 Ω , Low-Voltage, 4-Channel Analog Multiplexer

Detailed Description

The MAX4734 is a low 0.8 Ω max (at $V_+ = 2.7V$) on-resistance, low-voltage, 4-channel CMOS analog multiplexer that operates from a 1.6V to 3.6V single supply. CMOS switch construction allows switching analog signals that range from GND to V_+ .

When powered from a 2.7V supply, the 0.8 Ω max R_{ON} allows high continuous currents to be switched in a variety of applications.

Applications Information

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence V_+ on first, followed by NO_1 or COM.

Although it is not required, power-supply bypassing improves noise margin and prevents switching noise propagation from the V_+ supply to other components. A 0.1 μF capacitor, connected from V_+ to GND, is adequate for most applications.

Logic Inputs

The MAX4734 logic inputs can be driven up to 3.6V regardless of the supply voltage. For example, with a 1.8V supply, A_1 and EN may be driven low to GND and high to 3.6V. Driving A_1 and EN rail-to-rail minimizes power consumption.

Analog Signal Levels

Analog signals that range over the entire supply voltage (V_+ to GND) can be passed with very little change in on-resistance (see *Typical Operating Characteristics*). The switches are bidirectional, so the NO_1 and COM pins can be used as either inputs or outputs.

Layout

High-speed switches require proper layout and design procedures for optimum performance. Reduce stray inductance and capacitance by keeping traces short and wide. Ensure that bypass capacitors are as close to the device as possible. Use large ground planes where possible.

Test Circuits/Timing Diagrams

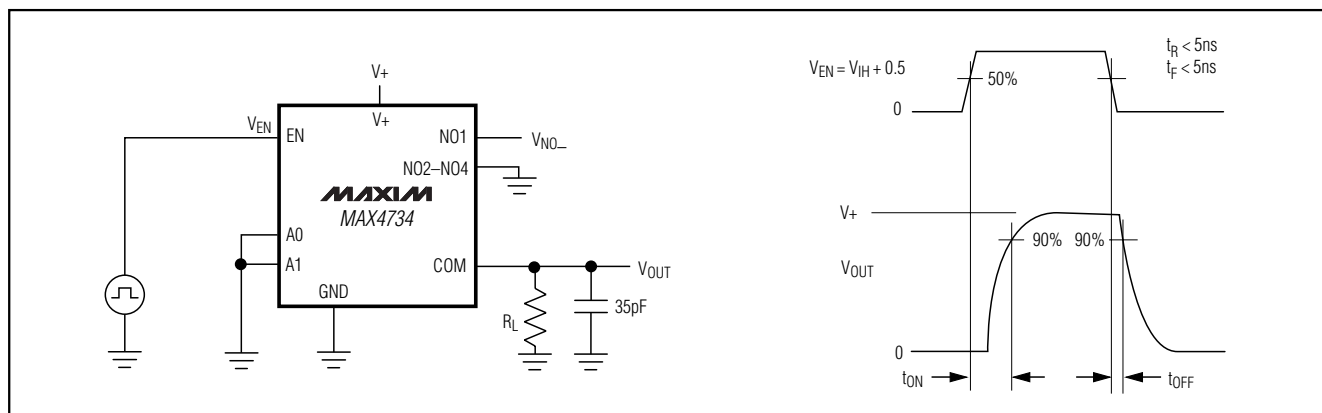


Figure 1. Switching Time

0.8 Ω , Low-Voltage, 4-Channel Analog Multiplexer

Test Circuits/Timing Diagrams (continued)

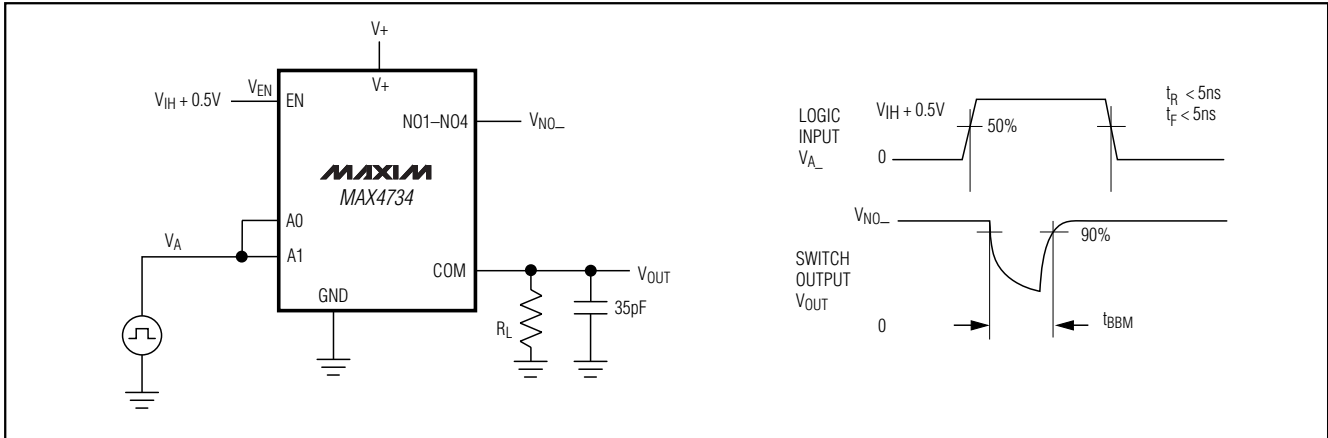


Figure 2. Break-Before-Make Interval

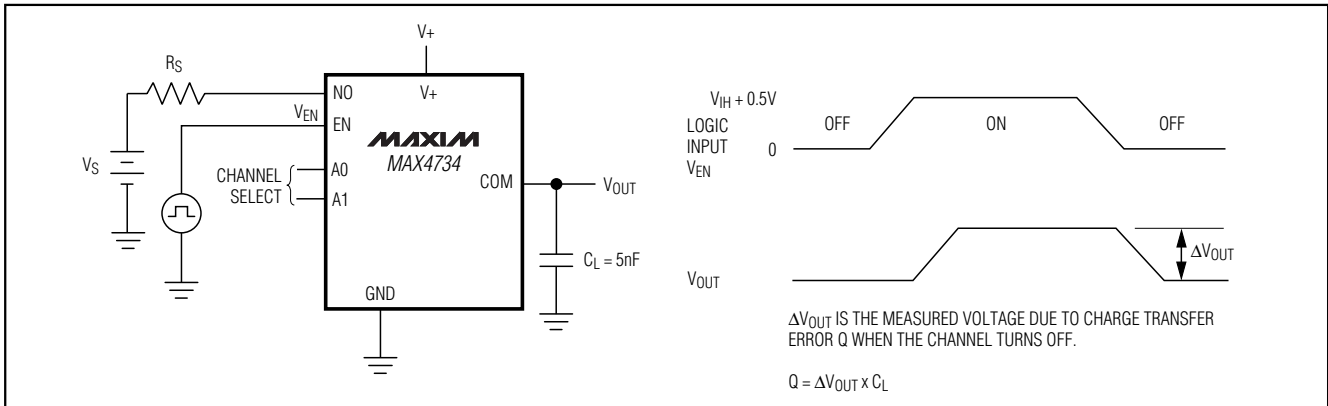


Figure 3. Charge Injection

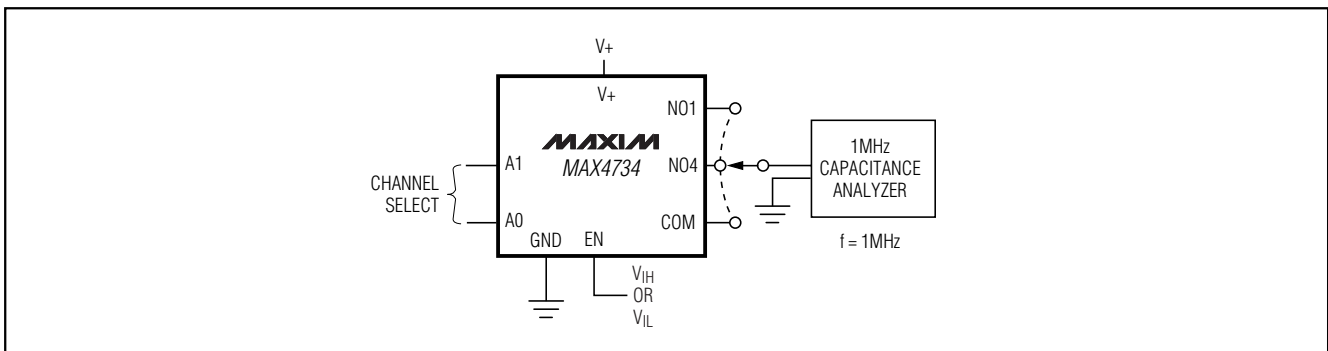


Figure 4. Channel Off/On-Capacitance

0.8Ω, Low-Voltage, 4-Channel Analog Multiplexer

Test Circuits/Timing Diagrams (continued)

MAX4734

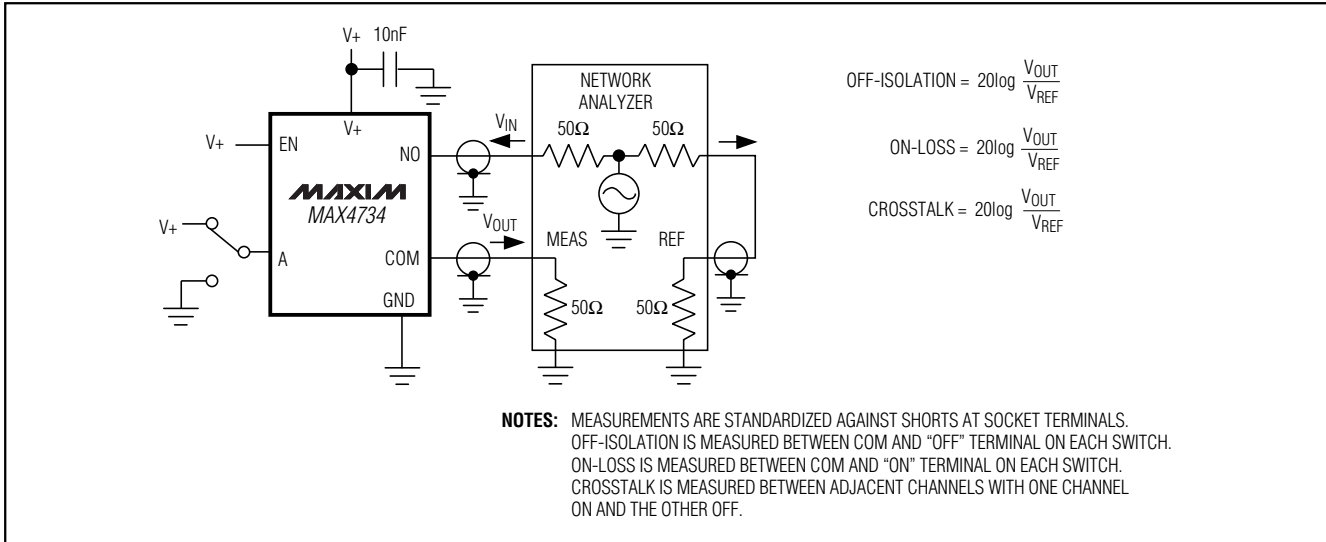


Figure 5. Off-Isolation/On-Channel/Crosstalk Bandwidth

Chip Information

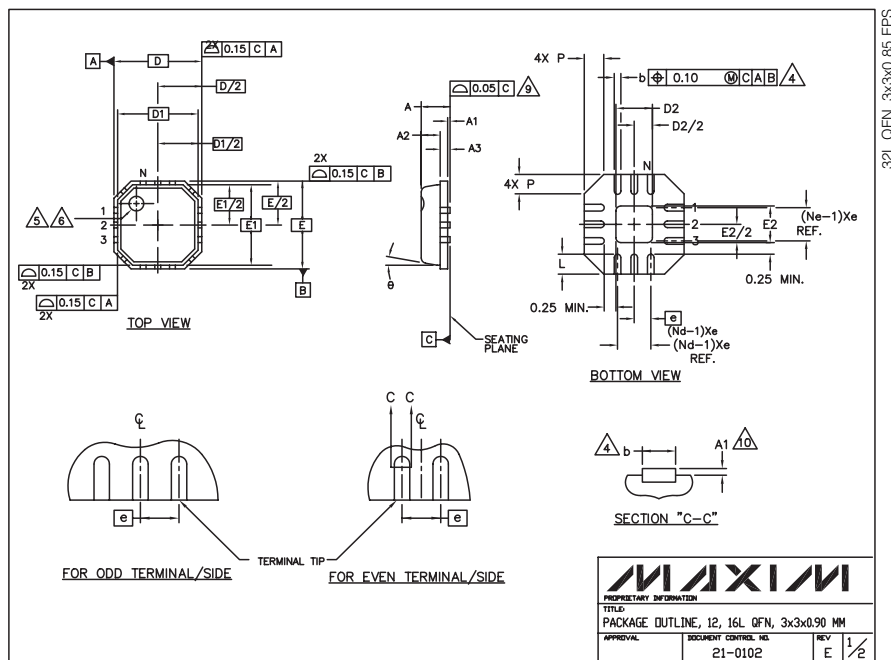
TRANSISTOR COUNT: 379

PROCESS: CMOS

0.8Ω, Low-Voltage, 4-Channel Analog Multiplexer

Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)



NOTES:

1. DIE THICKNESS ALLOWABLE IS 0.305mm MAXIMUM (.012 INCHES MAXIMUM)
2. DIMENSIONING & TOLERANCES CONFORM TO ASME Y14.5M. - 1994.
3. N IS THE NUMBER OF TERMINALS.
Nd IS THE NUMBER OF TERMINALS IN X-DIRECTION &
Ny IS THE NUMBER OF TERMINALS IN Y-DIRECTION.
4. DIMENSION B APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.20 AND 0.25mm FROM TERMINAL TIP.
5. THE PIN #1 IDENTIFIER MUST EXIST ON THE TOP SURFACE OF THE PACKAGE BY USING INDENTATION MARK OR INK/ LASER MARKED.
6. EXACT SHAPE AND SIZE OF THIS FEATURE IS OPTIONAL.
7. ALL DIMENSIONS ARE IN MILLIMETERS.
8. PACKAGE WARPAGE MAX 0.05mm.
9. APPLIED FOR EXPOSED PAD AND TERMINALS.
EXCLUDE EMBEDDING PART OF EXPOSED PAD FROM MEASURING.
10. MEETS JEDEC M0220.
11. THIS PACKAGE OUTLINE APPLIES TO ANVIL SINGULATION (STEPPED SIDES) AND TO SAW SINGULATION (STRAIGHT SIDES) QFN STYLES.

S T R E S S	COMMON DIMENSIONS			R ₀
	MIN.	NOM.	MAX.	
A	0.80	0.90	1.00	
A1	0.00	0.01	0.05	
A2	0.00	0.65	1.00	
A3		0.20 REF.		
D		3.00 BSC		
D1		2.75 BSC		
E		3.00 BSC		
E1		2.75 BSC		
Ø	0"		12"	
P	0		0.60	
D2	0.25		1.65	
F2	0.25		1.65	

s _{no}	PITCH VARIATION C			s _{no}	PITCH VARIATION D			s _{no}
	MIN.	NOM.	MAX.		MIN.	NOM.	MAX.	
10	0.50 BSC			10	0.50 BSC			
N	12			3	N	16		3
Nd	3			3	Nd	4		3
Ne				3	Ne			3
L	0.35	0.55	0.75	4	L	0.30	0.40	0.50
N	0.18	0.23	0.30	4	N	0.18	0.23	0.30

		
PROPRIETARY INFORMATION		
TITLE PACKAGE OUTLINE, 12, 16L QFN, 3x3x0.90 MM		
APPROVAL	DOCUMENT CONTROL NO. 21-0102	REV E

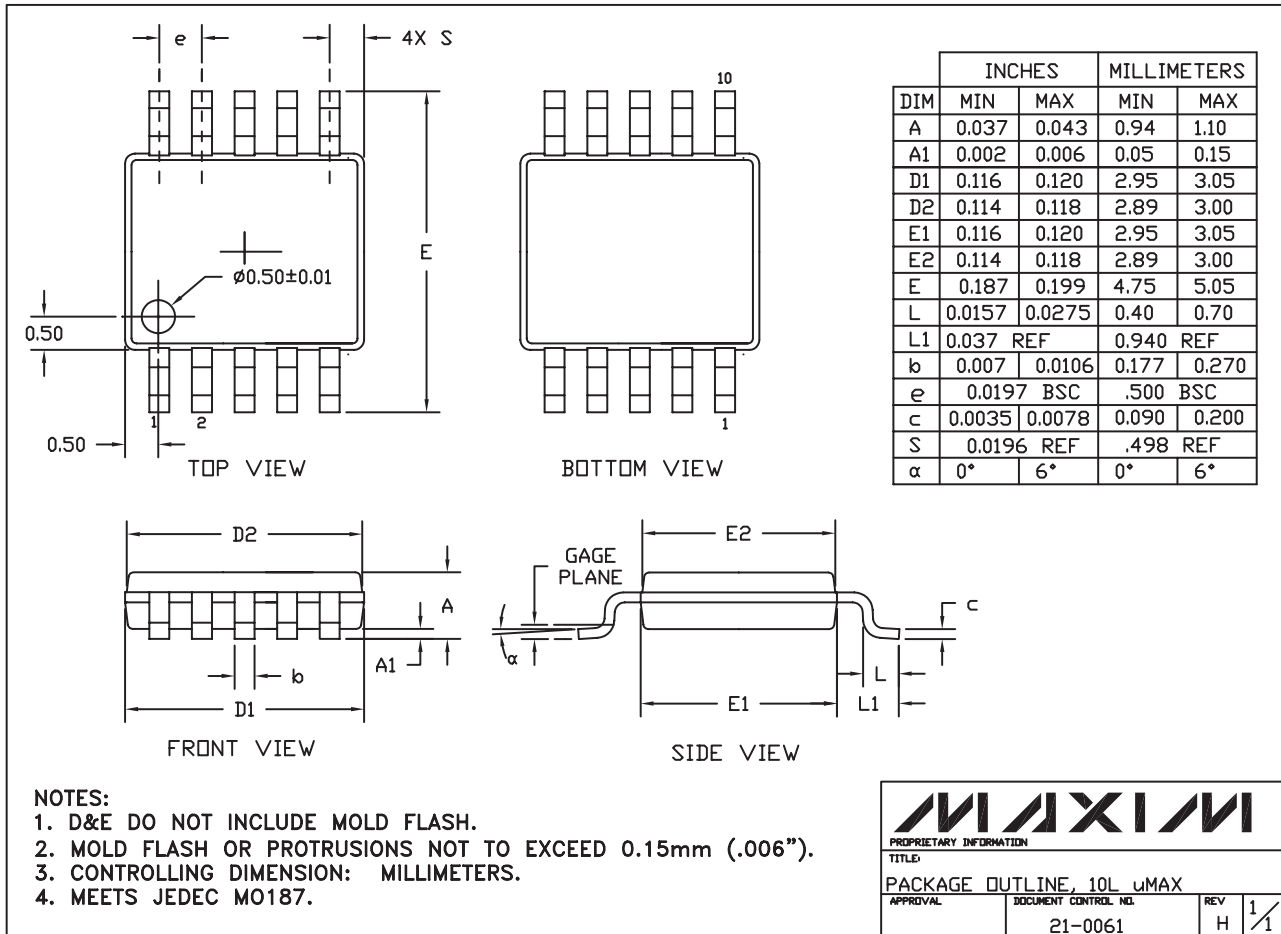
0.8Ω, Low-Voltage, 4-Channel Analog Multiplexer

Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)

10LUMAX.EPS

MAX4734



Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

Maxim Integrated Products, 120 San Gabriel Drive, Sunnyvale, CA 94086 408-737-7600 11